FEATURES • 125 °C T_J operation ($V_R < 5 V$)

- · Center tap module
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- · High frequency operation
- High power discrete
- · Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · New fully transfer-mold low profile, small footprint, high current package
- · Designed and gualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Note

This datasheet provides information about parts that are RoHS-compliant and/or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information/tables in this datasheet for details.

DESCRIPTION

The center tap Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

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MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	110	A				
V _{RRM}		15	V				
I _{FSM}	t _p = 5 μs sine	5050	A				
V _F	55 A _{pk} , T _J = 75 °C (per leg)	0.33	V				
TJ	Range	-55 to +125	°C				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VS-115CNQ015APbF	UNITS			
Maximum DC reverse voltage	V _R	T _J = 100 °C	15	V			
Maximum working peak reverse voltage	V _{RWM}	T _J = 125 °C	5	v			

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1

High Performance Schottky Rectifier New Generation 3, D-61 Package, 2 x 55 A

Base

common cathode

95

Common

cathode

Anode

1

53

Anode

2

172	Anode Comm 1 catho	non Anode
D-61-8-SM		
VS-115CNQ015ASLPbF	Bas comm catho 1 Anode 1	ion
PRODUCT SUMMAR	RY	
Package	D-61-8, D-61-8-SI	M, D-61-8-SL
I _{F(AV)}	2 x 55	A
I _{F(AV)} V _R	2 x 55 15 V	
V _R	15 V	/
V _R V _F at I _F	15 V 0.37 V	/ 100 °C
V _R V _F at I _F I _{RM} max.	15 V 0.37 V 1200 mA at	/ 100 °C C
V _R V _F at I _F I _{RM} max. T _J max.	15 V 0.37 V 1200 mA at 125 °C	/ 100 °C C athode

VS-115CNQ015APbF

VS-115CNQ015ASMPbF





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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward currentper legSee fig. 5per device		_		55	А	
		I _{F(AV)}	50 % duty cycle at T_C = 112 °C, rectangular waveform			110
Maximum peak one cycle non-repetitive surge current per leg See fig. 7			5 µs sine or 3 µs rect. pulse	Following any rated	5050	A
		I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	830	
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 4.5 mH		54	mJ
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 3 x V _B typical		2	А

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		55 A	T.I = 25 °C	0.37	V
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	110 A	1j=25 0	0.46	
See fig. 1	VFM (")	55 A	T 75 %C	0.33	
		110 A	T _J = 75 °C	0.43	
	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	20	
Maximum reverse leakage current per leg		T _J = 100 °C	$v_{\rm R} = naleu v_{\rm R}$	1200	
See fig. 2		T _J = 100 °C	V _R = 12 V	900	mA
		T _J = 100 °C	V _R = 5 V	540	
Maximum junction capacitance per leg		$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		5500	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		5.5	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction tempera	ature range	TJ		-55 to +125	о°С	
Maximum storage tempera	ture range	T _{Stg}		-55 to +150	U	
Maximum thermal resistance, junction to case per leg		Р	DC operation See fig. 4	0.5		
Maximum thermal resistance, junction to case per package		- R _{thJC}	DC operation	0.25 °C/W		
Typical thermal resistance, case to heatsink (D-61-8 only)		R _{thCS}	Mounting surface, smooth and greased Device flatness < 5 mils	0.30		
Approvimate weight				7.8	g	
Approximate weight	Approximate weight			0.28	oz.	
Mounting torque minimum				40 (35)	kgf · cm	
(D-61-8 only)	maximum			58 (50)	(lbf · in)	
Marking device			Case style D-61-8	115CN	Q015A	
			Case style D-61-8-SM	115CNQ	015ASM	
			Case style D-61-8-SL	115CNQ	015ASL	

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VS-115CNQ015APbF Series

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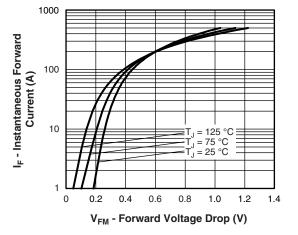
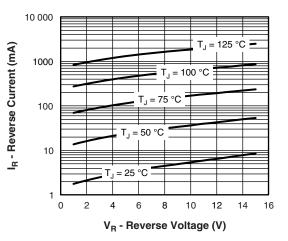
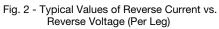


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





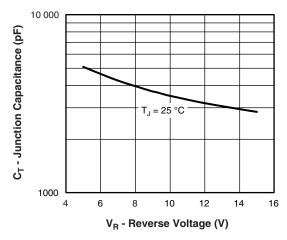


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

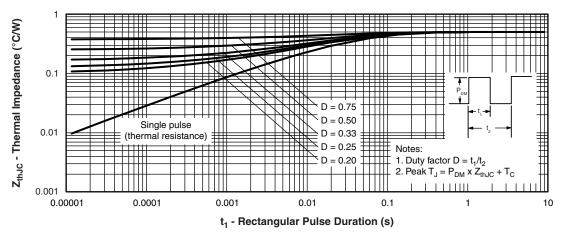
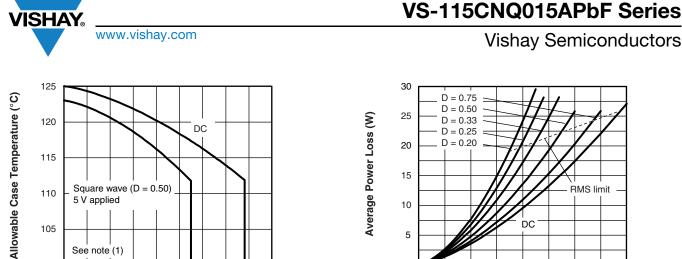


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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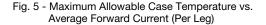
90

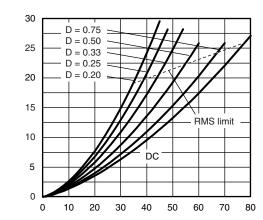
20 30 40 10 50 60 70 80 I_{F(AV)} - Average Forward Current (A)

See note (1)

100

0





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I_{F(AV)} - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics (Per Leg)

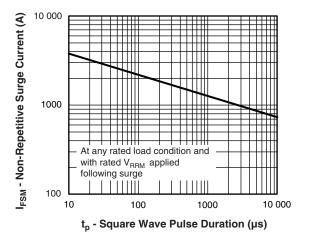


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

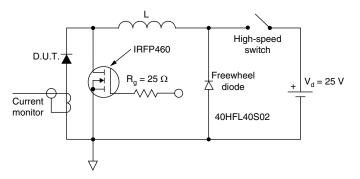


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{5} \ \mathsf{V} \end{array}$

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VS-115CNQ015APbF Series





ORDERING INFORMATION TABLE

Device code	VS-	115	с	Ν	Q	015	Α	PbF
	1	2	3	4	5	6	7	8
	 Vishay Semiconductors product Current rating (110 A) Circuit configuration: C = common cathode 							
	4 - Package:							
	N = D-61 5 - Schottky "Q" series 6 - Voltage rating (015 = 15 V) 7 - Package style:							
	• A = D-61-8 • ASM = D-61-8-SM							
	_		SIVI = D-6		1			
	8	•						
	•							

Standard pack quantity: A = 10 pieces; ASM/ASL = 20 pieces

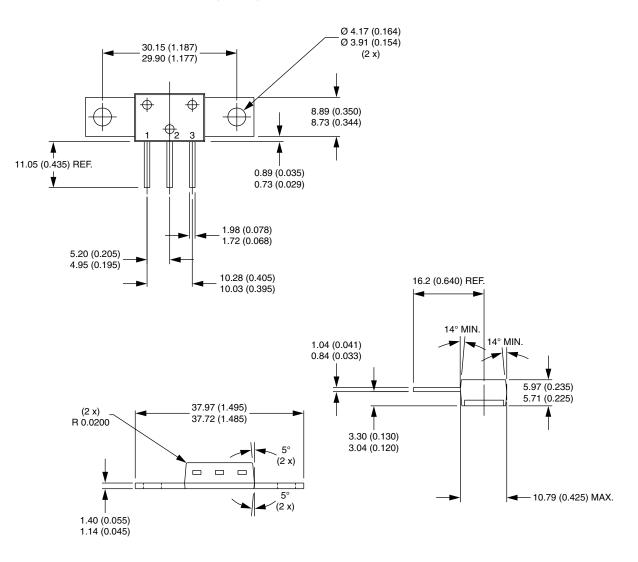
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95354					
Part marking information	www.vishay.com/doc?95356				

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D-61-8, D-61-8-SM, D-61-8-SL

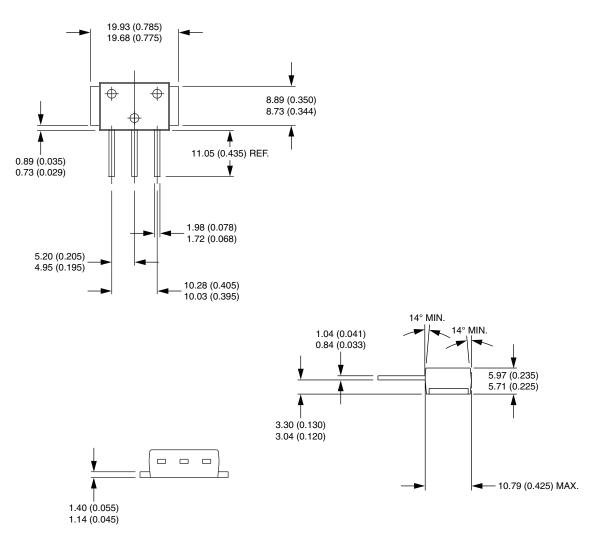
DIMENSIONS - D-61-8 in millimeters (inches)





DIMENSIONS - D-61-8-SM in millimeters (inches)

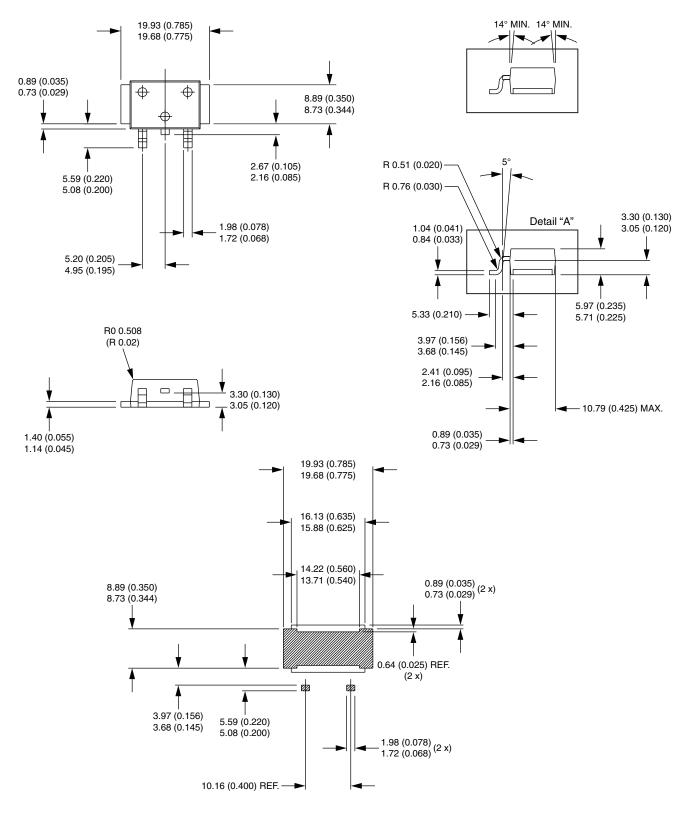
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DIMENSIONS - D-61-8-SL in millimeters (inches)

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